

TLE42744

Low Dropout Linear Voltage Regulator

TLE42744DV50 TLE42744GV50 TLE42744EV50 TLE42744GV33 TLE42744DV33 TLE42744GSV33

Data Sheet

Rev. 1.3, 2018-03-05

Automotive Power



Low Dropout Linear Voltage Regulator

TLE42744





1 Overview

Features

- · Very Low Current Consumption
- Output Voltages 5 V and 3.3 V ±2%
- Output Current up to 400 mA
- Very Low Dropout Voltage
- · Output Current Limitation
- Reverse Polarity Protection
- Overtemperature Shutdown
- Wide Temperature Range From -40 °C up to 150 °C
- Green Product (RoHS compliant)
- AEC Qualified



PG-TO252-3



PG-SSOP-14 exposed pad



PG-TO263-3



PG-SOT223-4

Description

The TLE42744 is a monolithic integrated low dropout voltage regulator for load currents up to 400 mA. An input voltage up to 40 V is regulated to $V_{\rm Q,nom}$ = 5 V / 3.3 V with a precision of ±2%. The device is designed for the harsh environment of automotive applications. Therefore it is protected against overload, short circuit and overtemperature conditions by the implemented output current limitation and the overtemperature shutdown circuit. The TLE42744 can be also used in all other applications requiring a stabilized 5 V / 3.3 V voltage.

Due to its very low quiescent current the TLE42744 is dedicated for use in applications permanently connected to $V_{\rm BAT}$.

Туре	Package	Marking
TLE42744DV50	PG-TO252-3	42744V5
TLE42744GV50	PG-TO263-3	42744V5
TLE42744EV50	PG-SSOP-14 exposed pad	42744V5
TLE42744DV33	PG-TO252-3	4274433
TLE42744GV33	PG-TO263-3	42744V33
TLE42744GSV33	PG-SOT223-4	427443



Block Diagram

2 Block Diagram

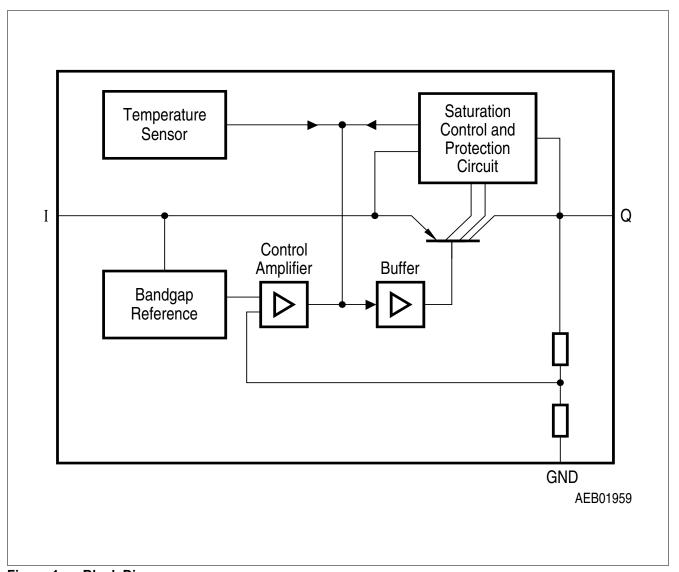


Figure 1 Block Diagram



Pin Configuration

3 Pin Configuration

3.1 Pin Assignment PG-TO252-3, PG-TO263-3 and PG-SOT223-4

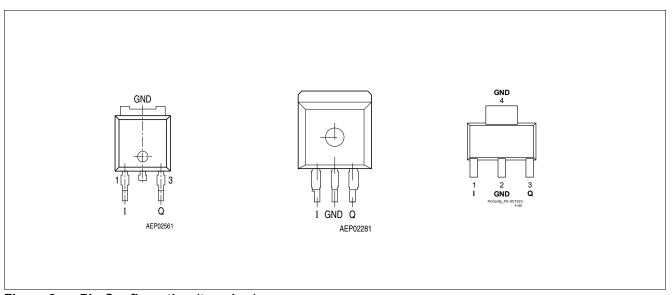


Figure 2 Pin Configuration (top view)

3.2 Pin Definitions and Functions PG-TO252-3, PG-TO263-3 and PG-SOT223-4

Pin No.	Symbol	Function
1	I	Input
		block to ground directly at the IC with a ceramic capacitor
2	GND	Ground
		internally connected to heat slug
3	Q	Output
		block to ground with a capacitor close to the IC terminals, respecting the values given
		for its capacitance and ESR in "Functional Range" on Page 6
4 / Heat Slug	_	Heat Slug
		internally connected to GND;
		connect to GND and heatsink area



Pin Configuration

3.3 Pin Assignment PG-SSOP-14 exposed pad

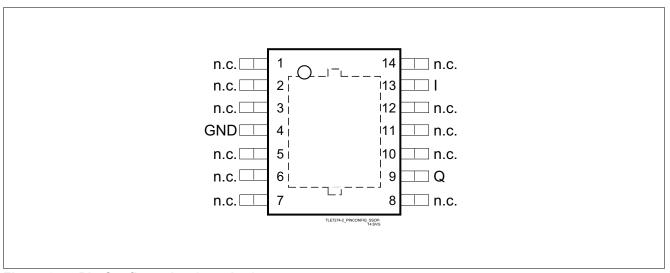


Figure 3 Pin Configuration (top view)

3.4 Pin Definitions and Functions PG-SSOP-14 exposed pad

Pin No.	Symbol	Function
1, 2, 3, 5, 6, 7	n.c.	Not connected
		can be open or connected to GND
4	GND	Ground
8, 10, 11, 12,	n.c.	Not connected
14		can be open or connected to GND
9	Q	Output block to ground with a capacitor close to the IC terminals, respecting the values given for its capacitance and ESR in "Functional Range" on Page 6
13	I	Input block to ground directly at the IC with a ceramic capacitor
Pad	_	Exposed Pad connect to GND and heatsink area



General Product Characteristics

4 General Product Characteristics

4.1 Absolute Maximum Ratings

Table 1 Absolute Maximum Ratings¹⁾

 T_i = -40 °C to 150 °C; all voltages with respect to ground, (unless otherwise specified)

Parameter	Symbol		Values	;	Unit	Note / Test Condition	Number
		Min.	Тур.	Max.			
Input I	"	•	1	1	-		•
Voltage	V_1	-42	_	45	V	_	P_4.1.1
Output Q	"	•	1	'			
Voltage	V_{Q}	-1	_	40	٧	_	P_4.1.2
Temperature					-		
Junction temperature	$T_{\rm j}$	-40	_	150	°C	_	P_4.1.3
Storage temperature	$T_{ m stg}$	-50	_	150	°C	_	P_4.1.4
ESD Susceptibility			ļ.				
ESD Absorption	$V_{ESD,HBM}$	-4	_	4	kV	Human Body Model (HBM) ²⁾	P_4.1.5
ESD Absorption	$V_{ESD,CDM}$	-1000	_	1000	V	Charge Device Model (CDM) ³⁾ at all pins	P_4.1.6

¹⁾ not subject to production test, specified by design

Notes

- 1. Stresses above the ones listed here may cause permanent damage to the device. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.
- 2. Integrated protection functions are designed to prevent IC destruction under fault conditions described in the data sheet. Fault conditions are considered as "outside" normal operating range. Protection functions are not designed for continuous repetitive operation.

4.2 Functional Range

Table 2 Functional Range

Parameter	Symbol		Value	S	Unit	Note / Test Condition	Number
		Min.	Тур.	Max.			
Input voltage	V_1	5.5	_	40	V	TLE42744DV50, TLE42744GV50, TLE42744EV50	P_4.2.1
Input voltage	V_1	4.7	_	40	V	TLE42744GV33, TLE42744DV33, TLE42744GSV33	P_4.2.2

²⁾ ESD susceptibility Human Body Model "HBM" according to AEC-Q100-002 - JESD22-A114

³⁾ ESD susceptibility Charged Device Model "CDM" according to ESDA STM5.3.1



General Product Characteristics

Table 2 Functional Range (cont'd)

Parameter	Symbol		Values			Note / Test Condition	Number
		Min.	Тур.	Max.			
Output Capacitor's Requirements for Stability	C_{Q}	22		_	μF	1)	P_4.2.3
Output Capacitor's Requirements for Stability	$ESR(C_{Q})$	_		3	Ω	2)	P_4.2.4
Junction temperature	T_{j}	-40		150	°C	_	P_4.2.5

¹⁾ the minimum output capacitance requirement is applicable for a worst case capacitance tolerance of 30%

Note: Within the functional or operating range, the IC operates as described in the circuit description. The electrical characteristics are specified within the conditions given in the Electrical Characteristics table.

4.3 Thermal Resistance

Note: This thermal data was generated in accordance with JEDEC JESD51 standards. For more information, go to www.jedec.org.

Table 3 Thermal Resistance

Parameter	Symbol	Values			Unit	Note / Test Condition	Number
		Min.	Тур.	Max.			
TLE42744DV50, TLE42744D	V33 (PG-TO252	-3)	+		·		
Junction to Case ¹⁾	R_{thJC}	_	3.6	_	K/W	measured to heat slug	P_4.3.1
Junction to Ambient ¹⁾	R_{thJA}	_	27	_	K/W	FR4 2s2p board ²⁾	P_4.3.2
Junction to Ambient ¹⁾	R_{thJA}	_	115	_	K/W	FR4 1s0p board, footprint only ³⁾	P_4.3.3
Junction to Ambient ¹⁾	R_{thJA}	-	52	_	K/W	FR4 1s0p board, 300 mm² heatsink area ³⁾	P_4.3.4
Junction to Ambient ¹⁾	R_{thJA}	-	40	_	K/W	FR4 1s0p board, 600 mm² heatsink area ³⁾	P_4.3.5
TLE42744GV50, TLE427440	GV33 (PG-TO263	-3)			·		
Junction to Case ¹⁾	R_{thJC}	_	3.6	_	K/W	measured to heat slug	P_4.3.6
Junction to Ambient ¹⁾	R_{thJA}	_	22	_	K/W	FR4 2s2p board ²⁾	P_4.3.7
Junction to Ambient ¹⁾	R_{thJA}	_	74	_	K/W	FR4 1s0p board, footprint only ³⁾	P_4.3.8
Junction to Ambient ¹⁾	R_{thJA}	-	42	_	K/W	FR4 1s0p board, 300 mm² heatsink area ³⁾	P_4.3.9
Junction to Ambient ¹⁾	R_{thJA}	_	34	_	K/W	FR4 1s0p board, 600 mm² heatsink area ³⁾	P_4.3.10

²⁾ relevant ESR value at f = 10 kHz



General Product Characteristics

Table 3 Thermal Resistance (cont'd)

Parameter	Symbol		Value	S	Unit	Note / Test Condition	Number
		Min.	Тур.	Max.			
TLE42744EV50 (PG-SSOP-	14 exposed pad)	Į.	+				1
Junction to Case ¹⁾	R_{thJC}	_	7	_	K/W	measured to exposed pad	P_4.3.11
Junction to Ambient ¹⁾	R_{thJA}	_	43	_	K/W	FR4 2s2p board ²⁾	P_4.3.12
Junction to Ambient ¹⁾	R_{thJA}	_	120	_	K/W	FR4 1s0p board, footprint only ³⁾	P_4.3.13
Junction to Ambient ¹⁾	R_{thJA}	-	59	_	K/W	FR4 1s0p board, 300 mm² heatsink area ³⁾	P_4.3.14
Junction to Ambient ¹⁾	R_{thJA}	_	49	_	K/W	FR4 1s0p board, 600 mm² heatsink area ³⁾	P_4.3.15
TLE42744GSV33 (PG-SOT2	23-4)	-	-	-	*	1	•
Junction to Case ¹⁾	R_{thJC}	_	17	_	K/W	measured to heat slug	P_4.3.16
Junction to Ambient ¹⁾	R_{thJA}	_	54	_	K/W	FR4 2s2p board ²⁾	P_4.3.17
Junction to Ambient ¹⁾	R_{thJA}	-	139	_	K/W	FR4 1s0p board, footprint only ³⁾	P_4.3.18
Junction to Ambient ¹⁾	R_{thJA}	-	73	_	K/W	FR4 1s0p board, 300 mm² heatsink area ³⁾	P_4.3.19
Junction to Ambient ¹⁾	R_{thJA}	-	64	_	K/W	FR4 1s0p board, 600 mm² heatsink area ³⁾	P_4.3.20

¹⁾ Not subject to production test, specified by design.

²⁾ Specified R_{thJA} value is according to Jedec JESD51-2,-5,-7 at natural convection on FR4 2s2p board; The Product (Chip+Package) was simulated on a 76.2 x 114.3 x 1.5 mm³ board with 2 inner copper layers (2 x 70µm Cu, 2 x 35µm Cu). Where applicable a thermal via array under the exposed pad contacted the first inner copper layer.

³⁾ Specified R_{thJA} value is according to Jedec JESD 51-3 at natural convection on FR4 1s0p board; The Product (Chip+Package) was simulated on a 76.2 × 114.3 × 1.5 mm³ board with 1 copper layer (1 x 70 μ m Cu).



5 Electrical Characteristics

5.1 Electrical Characteristics Voltage Regulator

Table 4 Electrical Characteristics

 V_1 =13.5 V; T_1 = -40 °C to 150 °C; all voltages with respect to ground (unless otherwise specified)

Parameter	Symbol		Value	S	Unit	Note / Test Condition	Number
		Min.	Тур.	Max.			
Output Q	<u>'</u>	•		•		<u>'</u>	<u>'</u>
Output Voltage	V_{Q}	4.9	5.0	5.1	V	TLE42744DV50, TLE42744GV50, TLE42744EV50 5 mA < $I_{\rm Q}$ < 400 mA 6 V < $V_{\rm I}$ < 28 V	P_5.1.1
Output Voltage	V_{Q}	4.9	5.0	5.1	V	TLE42744DV50, TLE42744GV50, TLE42744EV50 5 mA < I_Q <200 mA 6 V < V_I < 40 V	P_5.1.2
Output Voltage	V_{Q}	3.23	3.3	3.37	V	TLE42744GV33, TLE42744DV33, TLE42744GSV33; 5 mA < $I_{\rm Q}$ < 400 mA 4.7 V < $V_{\rm I}$ < 28 V	P_5.1.3
Output Voltage	V_{Q}	3.23	3.3	3.37	V	TLE42744GV33, TLE42744DV33, TLE42744GSV33; 5 mA < I_Q <200 mA 4.7 V < V_I < 40 V	P_5.1.4
Dropout Voltage	V_{dr}	_	250	500	mV	TLE42744DV50, TLE42744GV50, TLE42744EV50 $I_{\rm Q}$ = 250 mA $V_{\rm dr}$ = $V_{\rm I}$ - $V_{\rm Q}^{\rm 1}$)	P_5.1.5
Load Regulation	$\Delta V_{Q,lo}$	_	20	50	mV	TLE42744DV50, TLE42744GV50, TLE42744EV50; $I_{\rm Q}$ = 5 mA to 400 mA $V_{\rm I}$ = 6 V	P_5.1.6
Load Regulation	$\Delta V_{ m Q,lo}$	_	40	70	mV	TLE42744GV33, TLE42744DV33, TLE42744GSV33; $I_{\rm Q}$ = 5 mA to 300 mA	P_5.1.7
Line Regulation	$\Delta V_{Q,li}$	_	10	25	mV	$V_{\rm I}$ = 12 V to 32 V $I_{\rm Q}$ = 5 mA	P_5.1.8



Table 4 Electrical Characteristics (cont'd)

 $V_{\rm I}$ =13.5 V; $T_{\rm j}$ = -40 °C to 150 °C; all voltages with respect to ground (unless otherwise specified)

Parameter	Symbol		Value	S	Unit	Note / Test Condition	Number
		Min.	Тур.	Max.			
Output Current Limitation	I_{Q}	400	600	1100	mA	1)	P_5.1.9
Power Supply Ripple Rejection ²⁾	PSRR	_	60	_	dB	$f_{\rm r}$ = 100 Hz; $V_{\rm r}$ = 0.5 Vpp	P_5.1.10
Temperature Output Voltage Drift	$\frac{dV_{Q}}{dT}$	_	0.5	-	mV/K	-	P_5.1.11
Overtemperature Shutdown Threshold	$T_{j,sd}$	151	_	200	°C	$T_{\rm j}$ increasing ²⁾	P_5.1.12
Overtemperature Shutdown Threshold Hysteresis	$T_{ m j,sdh}$	_	25	-	°C	$T_{\rm j}$ decreasing ²⁾	P_5.1.13
Current Consumption			*	*			
Quiescent Current $I_{q} = I_{l} - I_{Q}$	I_{q}	_	100	220	μΑ	$I_{\rm Q}$ = 1 mA	P_5.1.14
Current Consumption $I_q = I_1 - I_Q$	I_{q}	_	8	15	mA	$I_{\rm Q}$ = 250 mA	P_5.1.15
Current Consumption $I_{q} = I_{l} - I_{Q}$	I_{q}	-	15	25	mA	TLE42744DV50, TLE42744GV50, TLE42744EV50; $I_{\rm Q}$ = 400 mA	P_5.1.16
Current Consumption $I_{q} = I_{l} - I_{Q}$	I_{q}	_	20	30	mA	TLE42744GV33, TLE42744DV33, TLE42744GSV33; $I_{\rm Q}$ = 400 mA	P_5.1.17

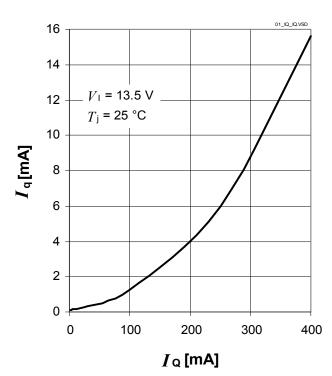
¹⁾ Measured when the output voltage $V_{\rm Q}$ has dropped 100 mV from the nominal value obtained at $V_{\rm I}$ = 13.5 V.

²⁾ not subject to production test, specified by design

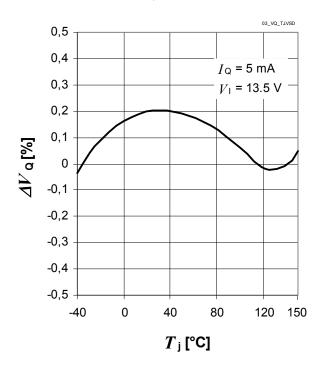


5.2 Typical Performance Characteristics Voltage Regulator

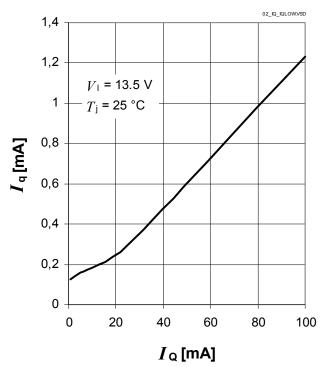
Current Consumption $I_{\rm q}$ versus Output Current $I_{\rm Q}$



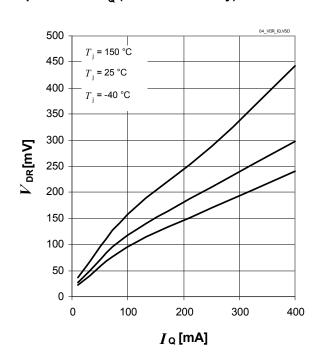
Output Voltage Variation ΔV_{Q} versus Junction Temperature T_{J}



Current Consumption $I_{\rm q}$ versus Low Output Current $I_{\rm O}$

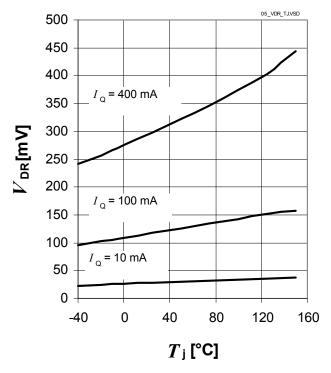


Dropout Voltage V_{dr} versus Output Current I_{Q} (5 V versions only)

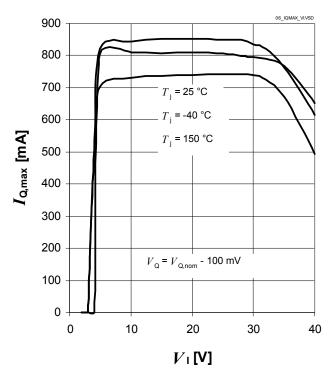




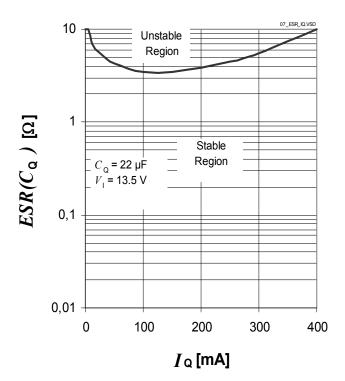
Dropout Voltage $V_{\rm dr}$ versus Junction Temperature (5 V versions only)



Maximum Output Current I_{Q} versus Input Voltage V_{I}



Region Of Stability: Output Capacitor's ESR $ESR(C_{\rm Q})$ versus Output Current $I_{\rm Q}$





Application Information

6 Application Information

Note: The following information is given as a hint for the implementation of the device only and shall not be regarded as a description or warranty of a certain functionality, condition or quality of the device.

6.1 Application Diagram

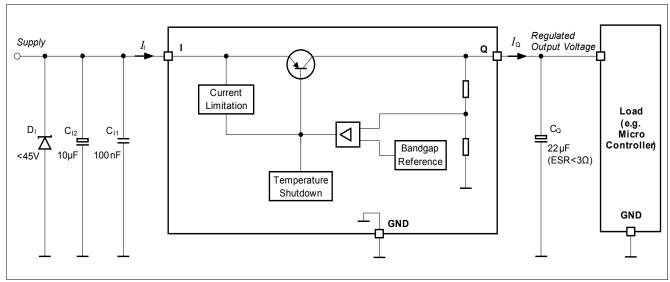


Figure 4 Application Diagram

6.2 Selection of External Components

6.2.1 Input Pin

The typical input circuitry for a linear voltage regulator is shown in the application diagram above.

A ceramic capacitor at the input, in the range of 100 nF to 470 nF, is recommended to filter out the high frequency disturbances imposed by the line e.g. ISO pulses 3a/b. This capacitor must be placed very close to the input pin of the linear voltage regulator on the PCB.

An aluminum electrolytic capacitor in the range of 10 μ F to 470 μ F is recommended as an input buffer to smooth out high energy pulses, such as ISO pulse 2a. This capacitor should be placed close to the input pin of the linear voltage regulator on the PCB.

An overvoltage suppressor diode can be used to further suppress any high voltage beyond the maximum rating of the linear voltage regulator and protect the device against any damage due to over-voltage.

The external components at the input are not mandatory for the operation of the voltage regulator, but they are recommended in case of possible external disturbances.

6.2.2 Output Pin

An output capacitor is mandatory for the stability of linear voltage regulators.

The requirement to the output capacitor is given in "Functional Range" on Page 6. The graph "Region Of Stability: Output Capacitor's ESR ESR(CQ) versus Output Current IQ" on Page 12 shows the stable operation range of the device.



Application Information

TLE42744 is designed to be stable with extremely low ESR capacitors. According to the automotive environment, ceramic capacitors with X5R or X7R dielectrics are recommended.

The output capacitor should be placed as close as possible to the regulator's output and GND pins and on the same side of the PCB as the regulator itself.

In case of rapid transients of input voltage or load current, the capacitance should be dimensioned in accordance and verified in the real application that the output stability requirements are fulfilled.

6.3 Thermal Considerations

Knowing the input voltage, the output voltage and the load profile of the application, the total power dissipation can be calculated:

$$P_{D} = (V_{I} - V_{Q}) \times I_{Q} + V_{I} \times I_{q}$$

$$(1)$$

with

- $P_{\rm D}$: continuous power dissipation
- V_1 : input voltage
- V_{Ω} : output voltage
- $I_{\rm O}$: output current
- I_q : quiescent current

The maximum acceptable thermal resistance $R_{th,JA}$ can then be calculated:

$$R_{thJA, max} = \frac{T_{j, max} - T_a}{P_D}$$
 (2)

with

- T_{i,max}: maximum allowed junction temperature
- T_a: ambient temperature

Based on the above calculation the proper PCB type and the necessary heat sink area can be determined with reference to the specification in "Thermal Resistance" on Page 7.

Example

Application conditions:

$$V_1 = 13.5 \text{ V}$$

$$V_{\rm O}$$
 = 5 V

$$I_{\rm O}$$
 = 250 mA

$$T_{\rm a}$$
 = 85 °C

Calculation of $R_{th,JA,max}$:

$$P_{\rm D} = (V_{\rm I} - V_{\rm Q}) \cdot I_{\rm Q} + V_{\rm I} \cdot I_{\rm q}$$

= (13.5 V - 5 V) \cdot 250 mA + 13.5 V \cdot 15 mA
= 2.125 W + 0.2025 W
= 2.3275 W



Application Information

$$R_{\text{thJA,max}} = (T_{\text{j,max}} - T_{\text{a}}) / P_{\text{D}}$$

= (150 °C - 85 °C) / 2.3275 W
= 27.93 K/W

As a result, the PCB design must ensure a thermal resistance $R_{\rm thJA}$ lower than 27.93 K/W. By considering TLE42744GV50 (PG-TO263-3 package) and according to "Thermal Resistance" on Page 7, only the FR4 2s2p board is applicable.

6.4 Reverse Polarity Protection

TLE42744 is self protected against reverse polarity faults and allows negative supply voltage. External reverse polarity diode is not needed. However, the absolute maximum ratings of the device as specified in "Absolute Maximum Ratings" on Page 6 must be kept.

The reverse voltage causes several small currents to flow into the IC hence increasing its junction temperature. As the thermal shut down circuitry does not work in the reverse polarity condition, designers have to consider this in their thermal design.

7 Package Outlines

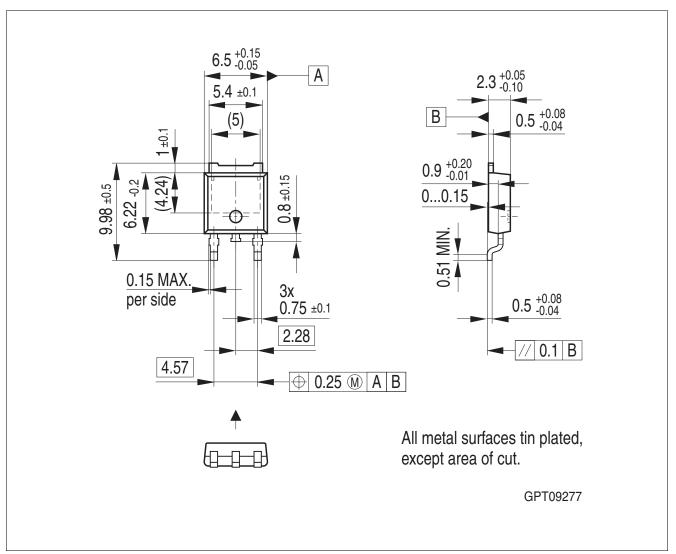


Figure 5 PG-TO252-3



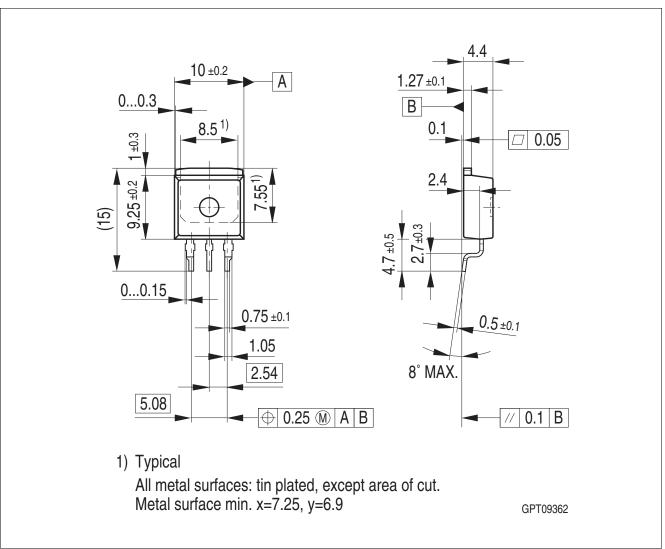


Figure 6 PG-TO263-3



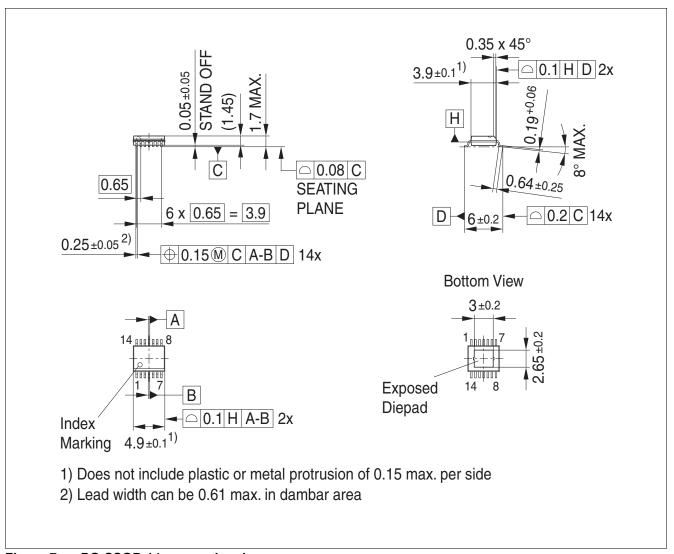


Figure 7 PG-SSOP-14 exposed pad



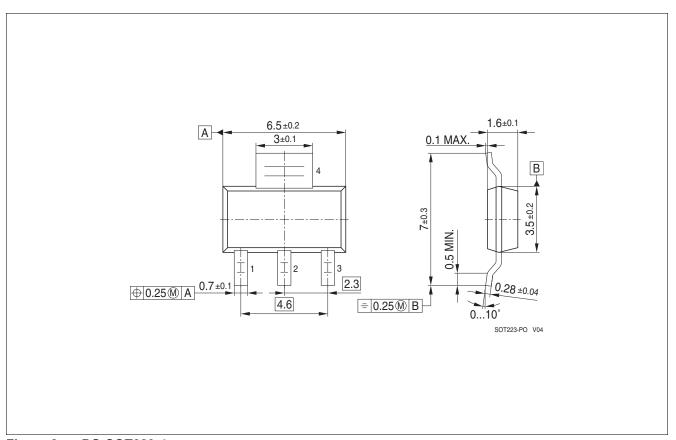


Figure 8 PG-SOT223-4

Green Product (RoHS compliant)

To meet the world-wide customer requirements for environmentally friendly products and to be compliant with government regulations the device is available as a green product. Green products are RoHS-Compliant (i.e Pb-free finish on leads and suitable for Pb-free soldering according to IPC/JEDEC J-STD-020).



Revision History

8 Revision History

Revision	Date	Changes
1.3	2018-03-05	Marking update in Chapter Overview (TLE42744GSV33 and TLE42744DV33) Updated Template on the last page.
1.2	2014-07-03	Application Information added. PG-TO252-3 and PG-SSOP-14 EP package outlines updated.
1.1	2010-01-13	Updated Version Data Sheet: version TLE42744EV50 in PG-SSOP-14 exposed pad and all related description added; 3.3V versions TLE42744GV33 in PG-TO263-3, TLE42744DV33 in PG-TO252-3 and TLE42744GSV33 in PG-SOT223-4 and all related description added
1.0	2009-01-14	Initial Version final Data Sheet

Trademarks

Edition 2018-03-05 Published by Infineon Technologies AG 81726 Munich, Germany

© 2018 Infineon Technologies AG. All Rights Reserved.

Do you have a question about any aspect of this document?

Email: erratum@infineon.com

IMPORTANT NOTICE

The information given in this document shall in no event be regarded as a guarantee of conditions or characteristics ("Beschaffenheitsgarantie").

With respect to any examples, hints or any typical values stated herein and/or any information regarding the application of the product, Infineon Technologies hereby disclaims any and all warranties and liabilities of any kind, including without limitation warranties of non-infringement of intellectual property rights of any third party.

In addition, any information given in this document is subject to customer's compliance with its obligations stated in this document and any applicable legal requirements, norms and standards concerning customer's products and any use of the product of Infineon Technologies in customer's applications.

The data contained in this document is exclusively intended for technically trained staff. It is the responsibility of customer's technical departments to evaluate the suitability of the product for the intended application and the completeness of the product information given in this document with respect to such application.

For further information on technology, delivery terms and conditions and prices, please contact the nearest Infineon Technologies Office (www.infineon.com).

WARNINGS

Due to technical requirements products may contain dangerous substances. For information on the types in question please contact your nearest Infineon Technologies office.

Except as otherwise explicitly approved by Infineon Technologies in a written document signed by authorized representatives of Infineon Technologies, Infineon Technologies' products may not be used in any applications where a failure of the product or any consequences of the use thereof can reasonably be expected to result in personal injury.